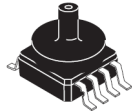
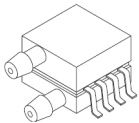




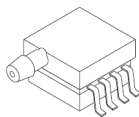
Integrated silicon pressure sensor, on-chip signal conditioned, temperature compensated and calibrated



MP3V5004GC6U/6T1
CASE 482A



MP3V5004DP
CASE 1351



MP3V5004GP
CASE 1369

Features

- Temperature Compensated from 10°C to 60°C
- Available in Gauge Surface Mount (SMT) Configuration
- Durable Thermoplastic (PPS) Package

Applications

- Washing Machine Water Level
- Ideally Suited for Microprocessor or Microcontroller-Based Systems

Description

The MP3V5004G series piezoresistive transducer is a state-of-the-art monolithic silicon pressure sensor designed for a wide range of applications, but particularly those employing a microcontroller or microprocessor with A/D inputs. This sensor combines a highly sensitive implanted strain gauge with advanced micromachining techniques, thin-film metallization, and bipolar processing to provide an accurate, high level analog output signal that is proportional to the applied pressure



1 Ordering information

Table 1. Ordering information

Device Name	Package Options	Case No.	# of Ports				Pressure Type		Device Marking
			None	Single	Dual	Gauge	Differential	Absolute	
Small Outline Package (MP3V5004 Series)									
MP3V5004GC6U	Rail	482A		•		•			MP3V5004G
MP3V5004GC6T1	Tape & Reel	482A		•		•			MP3V5004G
MP3V5004DP	Trays	1351			•		•		MP3V5004DP
MP3V5004GP	Trays	1369		•		•			MP3V5004GP

2 Operating characteristics

Table 2. Operating Characteristics ($V_S = 3.0$ Vdc, $T_A = 25^\circ\text{C}$ unless otherwise noted, $P_1 > P_2$).

Characteristic	Symbol	Min	Typ	Max	Unit
Pressure Range	P_{OP}	0	—	3.92 400	kPa mm H ₂ O
Supply Voltage ⁽¹⁾	V_S	2.7	3.0	3.3	V _{DC}
Supply Current	I_S	—	—	10	mAdc
Span at 306 mm H ₂ O (3 kPa) ⁽²⁾	V_{FSS}	—	1.8	—	V
Offset ⁽³⁾ (4)	V_{OFF}	0.45	0.6	0.75	V
SensitivityAccuracy ⁽⁴⁾ (5)	V/P	—	0.6	—	V/kPa mV/mm H ₂ O
0 to 100 mm H ₂ O (10 to 60°C)	—	—	5.9	—	
100 to 400 mm H ₂ O (10 to 60°C)	—	—	—	±1.5	%V _{FSS}
	—	—	—	±2.5	%V _{FSS}

- Device is ratiometric within this specified excitation range.
- Span is defined as the algebraic difference between the output voltage at specified pressure and the output voltage at the minimum rated pressure.
- Offset (V_{off}) is defined as the output voltage at the minimum rated pressure.
- Accuracy (error budget) consists of the following:
 Linearity: Output deviation from a straight line relationship with pressure over the specified pressure range.
 Temperature Hysteresis: Output deviation at any temperature within the operating temperature range, after the temperature is cycled to and from the minimum or maximum operating temperature points, with zero differential pressure applied.
 Pressure Hysteresis: Output deviation at any pressure within the specified range, when this pressure is cycled to and from the minimum or maximum rated pressure, at 25°C.
 Offset Stability: Output deviation, after 1000 temperature cycles, -30° to 100°C, and 1.5 million pressure cycles, with minimum rated pressure applied.
 TcSpan: Output deviation over the temperature range of 10° to 60°C, relative to 25°C.
 TcOffset: Output deviation with minimum rated pressure applied, over the temperature range of 10° to 60°C, relative to 25°C.
 Variation from Nominal: The variation from nominal values, for Offset or Full Scale Span, as a percent of VFSS, at 25°C.
- Auto-Zero at Factory Installation: Due to the sensitivity of the MP3V5004G, external mechanical stresses and mounting position can affect the zero pressure output reading. Auto-zeroing is defined as storing the zero pressure output reading and subtracting this from the device's output during normal operations. Reference AN1636 for specific information. The specified accuracy assumes a maximum temperature change of ±5°C between auto-zero and measurement

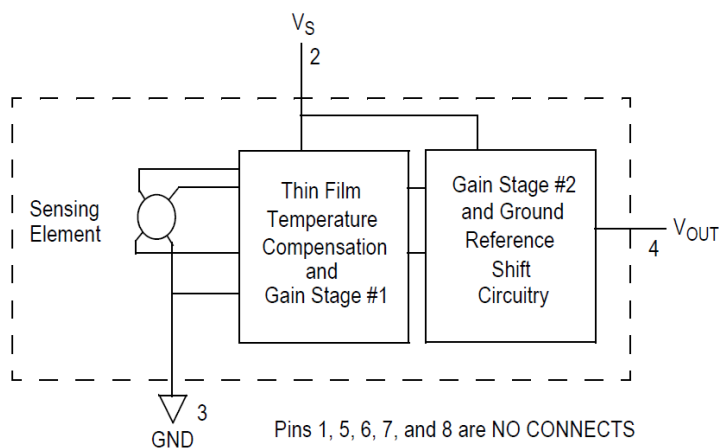
3 Maximum ratings

Table 3. Maximum Ratings⁽¹⁾

Rating	Symbol	Value	Units
Maximum Pressure ($P_1 > P_2$)	P_{MAX}	16	kPa
Storage Temperature	T_{STG}	-30 to +100	°C
Operating Temperature	T_A	0 to +85	°C

1. Exposure beyond the specified limits may cause permanent damage or degradation to the device.

Figure 1 shows a block diagram of the internal circuitry integrated on a pressure sensor chip.

Figure 1. Fully Integrated Pressure Sensor Schematic


4 On-chip temperature compensation and calibration

The performance over temperature is achieved by integrating the shear-stress strain gauge, temperature compensation, calibration and signal conditioning circuitry onto a single monolithic chip.

Figure 2 illustrates the gauge configuration in the basic chip carrier (Case 482A). A fluorosilicone gel isolates the die surface and wire bonds from the environment, while allowing the pressure signal to be transmitted to the silicon diaphragm.

The MP3V5004G series sensor operating characteristics are based on the use of dry air as pressure media. Media, other than dry air, may have adverse effects on sensor performance and long-term reliability. Internal reliability and qualification test for dry air, and other media, are available from the factory. Contact the factory for information regarding media tolerance in your application.

Figure 3 shows the recommended decoupling circuit for interfacing the output of the MP3V5004G to the A/D input of the microprocessor or microcontroller. Proper decoupling of the power supply is recommended.

Figure 4 shows the sensor output signal relative to pressure input. Typical, minimum and maximum output curves are shown for operation over a temperature range of 10°C to 60°C using the decoupling circuit shown in Figure 3. The output will saturate outside of the specified pressure range.

Figure 2. Cross Sectional Diagram SSOP (not to scale)

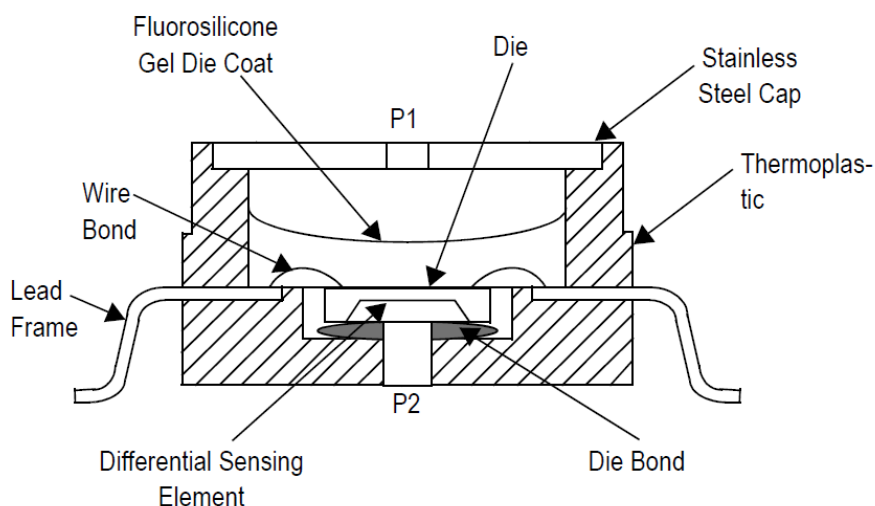


Figure 3. Recommended Power Supply Decoupling and Output Filtering. (For additional output filtering, please refer to Application Note AN1646.)

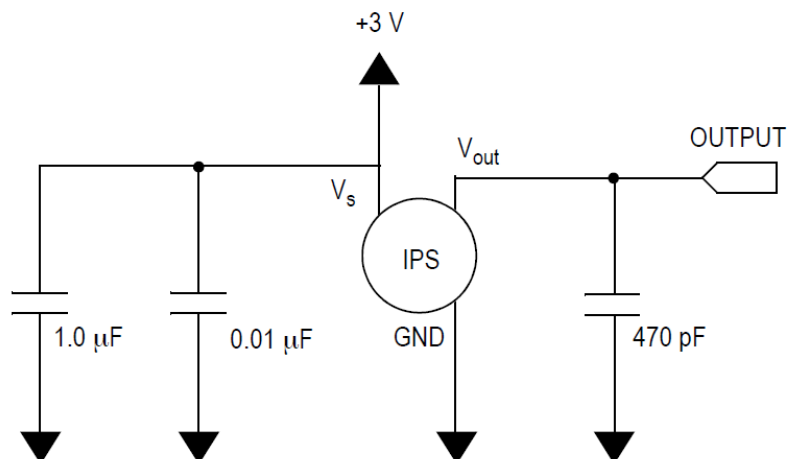
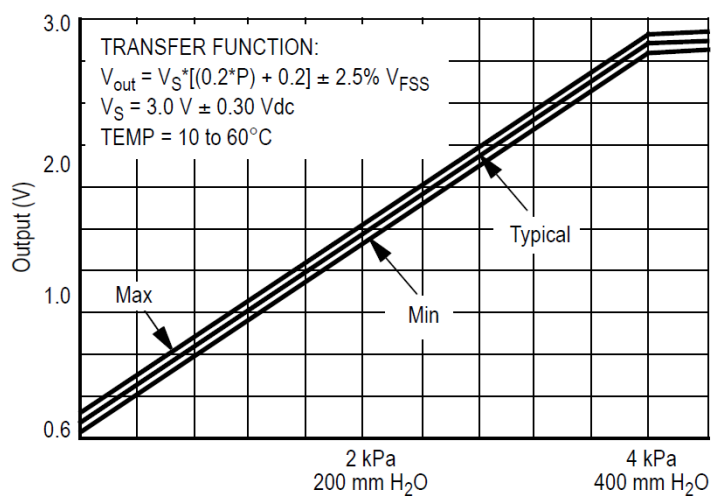


Figure 4. Output vs. Pressure Differential at $\pm 2.5\%$ VFSS (See Note 5 in Operating Characteristics table)





5 Pressure (P1) / Vacuum (P2) side identification table

ST designates the two sides of the pressure sensor as the Pressure (P1) side and the Vacuum (P2) side. The Pressure (P1) side is the side containing silicone gel which isolates the die from the environment. The ST pressure sensor is designed to operate with positive differential pressure applied, $P1 > P2$.

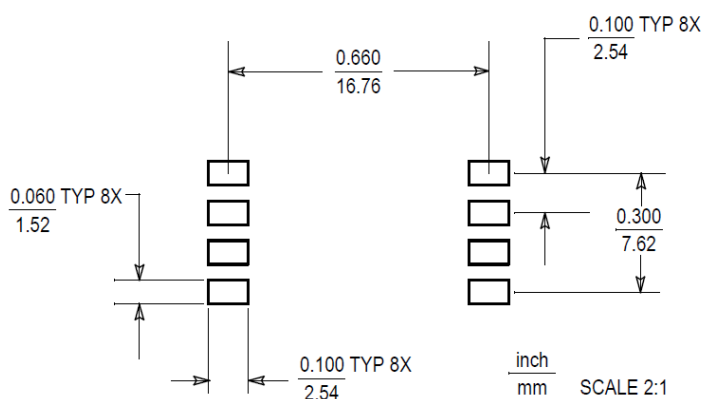
The Pressure (P1) side may be identified by using the table below.

Part Number	Case Type	Pressure (P1) Side Identifier
MP3V5004GC6U/T1	482A	Side with Port Attached
MP3V5004GP	1369	Side with Port Attached
MP3V5004DP	1351	Side with Part Marking

6 Minimum recommended footprint for small outline packages

Surface mount board layout is a critical portion of the total design. The footprint for the semiconductor package must be the correct size to ensure proper solder connection interface between the board and the package. With the correct pad geometry, the packages will self-align when subjected to a solder reflow process. It is always recommended to fabricate boards with a solder mask layer to avoid bridging and/or shorting between solder pads, especially on tight tolerances and/or tight layouts

Figure 5. SOP Footprint



7 PACKAGE DIMENSIONS

Figure 6. CASE 482A-01 ISSUE A SMALL OUTLINE PACKAGE

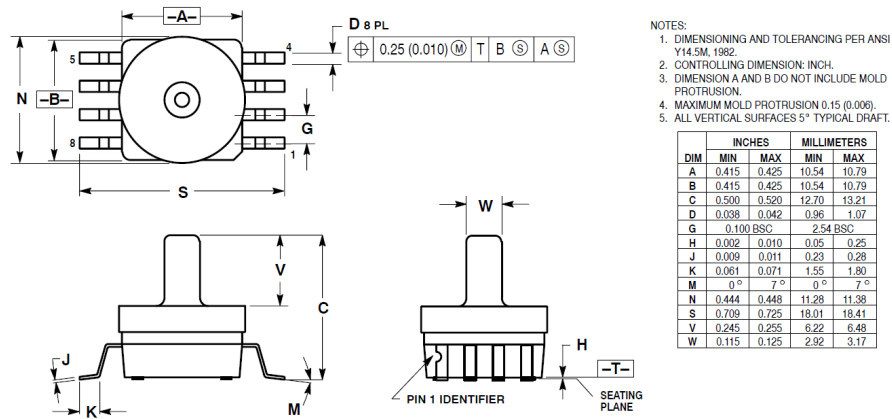
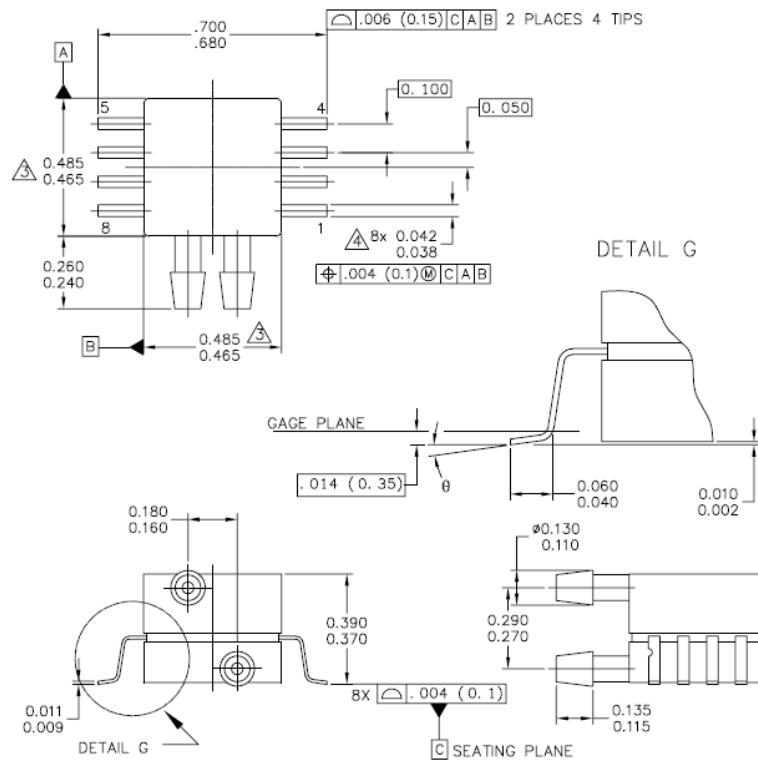


Figure 7. CASE 1351-01 ISSUE A SMALL OUTLINE PACKAGE



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TITLE: 8 LD SNSR, DUAL PORT	DOCUMENT NO: 98ASA99255D CASE NUMBER: 1351-01 STANDARD: NON-JEDEC	REV: A 27 JUL 2005



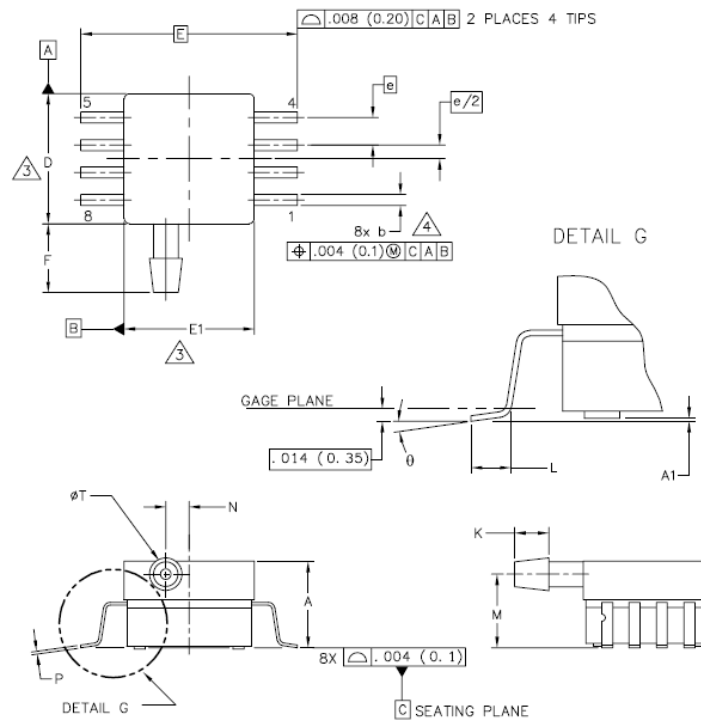
Figure 8. CASE 1351-01 ISSUE A SMALL OUTLINE PACKAGE

- NOTES:
- 1. CONTROLLING DIMENSION: INCH
 - 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.
 - 3. DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS. MOLD FLASH AND PROTRUSIONS SHALL NOT EXCEED .006 PER SIDE.
 - 4. DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE .008 MAXIMUM.

STYLE 1:	STYLE 2:
PIN 1: GND	PIN 1: N/C
PIN 2: +Vout	PIN 2: Vs
PIN 3: Vs	PIN 3: GND
PIN 4: -Vout	PIN 4: Vout
PIN 5: N/C	PIN 5: N/C
PIN 6: N/C	PIN 6: N/C
PIN 7: N/C	PIN 7: N/C
PIN 8: N/C	PIN 8: N/C

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TITLE: 8 LD SNSR, DUAL PORT		DOCUMENT NO: 98ASA99255D		REV: A	
		CASE NUMBER: 1351-01		27 JUL 2005	
		STANDARD: NON-JEDEC			

Figure 9. CASE 1369-01 ISSUE B SMALL OUTLINE PACKAGE



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TITLE: 8 LD SOP, SIDE PORT	DOCUMENT NO: 98ASA99303D		REV: B
	CASE NUMBER: 1369-01		24 MAY 2005
	STANDARD: NON-JEDEC		



Figure 10. CASE 1369-01 ISSUE B SMALL OUTLINE PACKAGE

NOTES:

1. CONTROLLING DIMENSION: INCH

2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.

 DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS.
MOLD FLASH AND PROTRUSIONS SHALL NOT EXCEED .006 (0.152) PER SIDE.

 DIMENSION DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR
PROTRUSION SHALL BE .008 (0.203) MAXIMUM.

INCHES			MILLIMETERS		INCHES			MILLIMETERS	
DIM	MIN	MAX	MIN	MAX	DIM	MIN	MAX	MIN	MAX
A	.300	.330	7.11	7.62	Ø	0*	7*	0*	7*
A1	.002	.010	0.05	0.25	-	----	----	----	----
b	.038	.042	0.96	1.07	-	----	----	----	----
D	.465	.485	11.81	12.32	-	----	----	----	----
E	.717 BSC		18.21 BSC		-	----	----	----	----
E1	.465	.485	11.81	12.32	-	----	----	----	----
e	.100 BSC		2.54 BSC		-	----	----	----	----
F	.245	.255	6.22	6.47	-	----	----	----	----
K	.120	.130	3.05	3.30	-	----	----	----	----
L	.061	.071	1.55	1.80	-	----	----	----	----
M	.270	.290	6.86	7.36	-	----	----	----	----
N	.080	.090	2.03	2.28	-	----	----	----	----
P	.009	.011	0.23	0.28	-	----	----	----	----
T	.115	.125	2.92	3.17	-	----	----	----	----
© FREESCALE SEMICONDUCTOR, INC. ALL RIGHTS RESERVED.			MECHANICAL OUTLINE			PRINT VERSION NOT TO SCALE			
TITLE: 8 LD SOP, SIDE PORT					DOCUMENT NO: 98ASA99303D			REV: B	
					CASE NUMBER: 1369-01			24 MAY 2005	
					STANDARD: NON-JEDEC				



Revision history

Table 4. Document revision history

Date	Revision	Changes
28-May-2026	1	Initial release from ST, rebranded NXP document



Contents

1	Ordering information	2
2	Operating characteristics	3
3	Maximum ratings	4
4	On-chip temperature compensation and calibration	5
5	Pressure (P1) / Vacuum (P2) side identification table	7
6	Minimum recommended footprint for small outline packages.....	8
7	PACKAGE DIMENSIONS	9
	Revision history	13
	List of tables	15
	List of figures.....	16



List of tables

Table 1. Ordering information. 2

Table 2. Operating Characteristics ($V_S = 3.0\text{ Vdc}$, $T_A = 25^\circ\text{C}$ unless otherwise noted, $P1 > P2$). 3

Table 3. Maximum Ratings⁽¹⁾ 4

Table 4. Document revision history 13



List of figures

Figure 1.	Fully Integrated Pressure Sensor Schematic	4
Figure 2.	Cross Sectional Diagram SSOP (not to scale)	5
Figure 3.	Recommended Power Supply Decoupling and Output Filtering. (For additional output filtering, please refer to Application Note AN1646.)	6
Figure 4.	Output vs. Pressure Differential at $\pm 2.5\%$ VFSS (See Note 5 in Operating Characteristics table)	6
Figure 5.	SOP Footprint	8
Figure 6.	CASE 482A-01 ISSUE A SMALL OUTLINE PACKAGE	9
Figure 7.	CASE 1351-01 ISSUE A SMALL OUTLINE PACKAGE	9
Figure 8.	CASE 1351-01 ISSUE A SMALL OUTLINE PACKAGE	10
Figure 9.	CASE 1369-01 ISSUE B SMALL OUTLINE PACKAGE	11
Figure 10.	CASE 1369-01 ISSUE B SMALL OUTLINE PACKAGE	12

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